Directional Emission from Leaky and Guided Modes in GaAs Nanowires Measured by Cathodoluminescence

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Abstract

We measure the polarization-resolved angular emission distribution from thin and thick GaAs nanowires (diameters ~110 and ~180 nm) with cathodoluminescence polarimetry. The nanowires, which horizontally rest on a thin carbon film, are excited by a 5 keV electron beam and emit band gap luminescence at a central wavelength of 870 nm. The emission can couple to different waveguide modes that propagate along the wire, are dependent on the wire diameter and determine the directionality and polarization of the emission. Although each measured nanowire can support different
modes, the polarized emission is dominated by the TM01 waveguide mode in all cases, independently of wire diameter. When exciting the nanowires close to the end facets, the thin and thick wires exhibit opposite directional emission. The emission from thin nanowires is dominated by a leaky TM01 mode that leads to emission towards the opposite end facet (emission to the right when exciting the left-side edge). For the thick wires, however, the TM01 mode is guided but also lossy due to absorption in the substrate. In such a case, the wires emit towards the excited end facet (to the left when exciting the left-side edge). The emission directionality switches for nanowire diameters in the range of 145-170 nm. We show that the measurements agree well with both a simple 1D current model and numerical simulations. The high spatial resolution of angle- and polarization-resolved cathodoluminescence spectroscopy provides detailed insight into the nanoscale emission and propagation of light in semiconductor nanowires.

Keywords

Cathodoluminescence, nanowires, GaAs, polarimetry, waveguide modes

Semiconductor nanowires have fueled a growing field of integrated nanoscale optoelectronic devices, such as lasers,1–3 light emitting diodes,4,5 photovoltaics,6–9 single-photon detectors,10–13 photodetectors14 and metamaterials.15,16 Both the electrical and optical properties of nanowires are eminently tunable by controlling their size, geometry or composition, among others.17–20 The directionality and polarization of emitted radiation from nanowires have been examined in previous studies14,21–23 and result from the coupling to leaky and guided waveguide modes,24–29 which can also be described by Mie and Fabry-Pérot resonances.29,30 All modes are highly dependent on nanowire diameter.

Most previous studies of semiconductor nanowire emission properties have employed optical excitation methods. While powerful, such techniques lack the nanoscale spatial resolution to uncover all the features of the radiative processes from these nanostructures. Here we
use cathodoluminescence (CL) spectroscopy, in which an electron beam acts as a highly localized excitation source and the emitted light is detected.\textsuperscript{31–33} The high spatial excitation resolution of CL is typically determined by the electron beam spot size and the evanescent field extent about the beam path (\textasciitilde10–30 nm),\textsuperscript{33} which enables the study of the nanoscale modal behavior of light.\textsuperscript{34–37} In general, CL also allows the characterization of a wide range of material properties.\textsuperscript{38–40} Recently, the ability to measure both the angular and polarization distribution in CL has been demonstrated.\textsuperscript{41,42}

In this article, we use these new CL features to investigate the angle- and polarization-dependent emission from horizontal GaAs nanowires.\textsuperscript{41} We study nanowires of different lengths and diameters that support both leaky and guided modes. Exciting the nanowires along their length, we find that the TM01 mode dominates the polarization-resolved emission for all excited wires, but depending on the diameter, the mode is either leaky or guided. We observe a distinct change of the directionality of the CL emission when exciting the nanowires close to their end facets, which correlates with the nanowire diameter and the nature of the mode. Thinner, leaky wires emit in the opposite direction from thicker, guided wires. The measurements exhibit good agreement with both a simple 1D current model and numerical simulations, which show that the substrate also plays a role in the emission directionality.

**Experiment**

GaAs nanowires were grown by self-catalyzed molecular beam epitaxy on silicon\textsuperscript{43,44} and were subsequently mechanically broken and deposited on a holey carbon TEM grid (see Methods). Scanning electron micrographs of the two GaAs nanowires studied here are shown in Figure 1(a). The thin NW1 has a length of 7.9 \( \mu \text{m} \) and a diameter of 100–120 nm, while the thick NW2 has a length of 12 \( \mu \text{m} \) and a diameter of 175–195 nm. Both wires are slightly tapered, the right-hand side being thinner, although NW2 does thicken again slightly at the very edge. The nanowires lie horizontally on the \textasciitilde20 nm thick carbon layer. In the
Figure 1: (a) Scanning electron micrographs of the GaAs nanowires NW1 (bottom) and NW2 (top), shown on the same scale. NW1 is 7.9 μm long and 100–120 nm thick; NW2 is 12 μm long and 175–195 nm thick. (b) Schematic overview of the cathodoluminescence polarimetry setup. The electron beam excites the nanowires, the emitted radiation is collected by a parabolic mirror and either focused onto a fiber connected to a spectrometer or sent through a QWP, linear polarizer and bandpass filter before being imaged onto a 2D CCD camera. (c) Dispersion relation of leaky and guided modes for infinitely long cylinders, showing the real part of the wavevector $k_y$ multiplied by the cylinder diameter $d$, as a function of $d$, for GaAs at $\lambda_0 = 850$ nm ($n = 3.6$, $k_0 = 7.39 \mu$m$^{-1}$). The vertical red dashed lines indicate the average diameters of the two wires. The inset shows the measured CL emission spectrum from NW2. The spectrum of NW1 (not shown) does not differ noticeably except for a lower intensity. The vertical black dashed line in the inset at $\lambda_0 = 850$ nm indicates the transmittance maximum of the bandpass filter used for the angular measurements, while the gray area indicates the 40 nm bandwidth of the filter.

Supporting Information we show data for an additional thin and thick wire (SEM images shown in Figure S1).

The cathodoluminescence spectroscopy and polarimetry setup$^{41,45,46}$ is schematically
shown in Figure 1(b). A parabolic mirror collects the radiation from the nanowires and directs it onto a spectrometer or images it onto a 2D camera to measure the angular intensity distribution for a given wavelength (using a bandpass filter). Polarization-resolved measurements are obtained by using a polarimeter composed of a quarter-wave plate (QWP) and a linear polarizer (Pol.), which determines the Stokes parameters of the emitted radiation. The full polarization can be detected in this way, obtaining information about the degree of polarization, its orientation, ellipticity, and handedness. Essentially, this allows the retrieval of any arbitrary polarization state, including the different electric field components and the phase difference between them.\textsuperscript{47} This is not possible using only a linear polarizer. We correct for the geometrical and polarization dependent transformations of the parabolic mirror on the measured emission\textsuperscript{41} (see Methods for more details about the CL measurements). For the measurements, the nanowires are aligned along the y-axis, as defined by the coordinate system shown in Figure 1(b). As we expect directional emission along the nanowire axis, this is the preferred orientation for the mirror to collect the radiation symmetrically. The CL emission spectrum from NW2 is shown in the inset of Figure 1(c) and is dominated by band-gap recombination centered around $\lambda_0 = 870$ nm. This emission can feed into waveguide modes supported by the nanowire, that depend on its diameter, and which can affect the polarization and directionality of the emitted radiation.\textsuperscript{22–24,28}

**Nanowire waveguide modes**

Figure 1(c) shows the dispersion relation of waveguide modes for infinitely long cylinders,\textsuperscript{48} calculated for GaAs at $\lambda_0 = 850$ nm ($n = 3.6$, $k_0 = 7.39$ $\mu$m$^{-1}$), the wavelength at which we filter the angle-resolved measurements. We follow the formalism used in Ref. 27 and determine the wavevector $k_y$ along the axis of the nanowire. We show the real part of $k_y$ multiplied by the wire diameter $d$, as a function of $d$. The dispersion curves denote transverse electric (TE), transverse magnetic (TM), and magnetoelectric (HE) modes. These modes are
characterized as “leaky” if their dispersion lies below the light line of air \((k_y < k_0)\), in which case they also possess a non-negligible imaginary part of the wavevector \(k_y\).\(^{27}\) If the mode dispersion lies above the light line of air but below the light line in GaAs \((k_{GaAs} > k_y > k_0)\), the waveguide mode is guided within the nanowire.

The vertical red dashed lines in Figure 1(c) display the average diameter of the two nanowires studied here. For the thin NW1 (and any nanowire with a diameter below 150 nm), only the TM01 and the HE11 modes are supported. Both are very close to the light line in air, but the TM01 mode is slightly below it and thus leaky for these diameters. In the case of the thicker NW2, the TE01, HE12 and TM02 also occur. The latter two are far below the light line in air and thus have a very short propagation length along the nanowire, while the HE11 mode is very clearly guided. The TE01 and TM01 modes are both very close to the light line of air in this region, representing a transition region between a leaky and guided nature for these modes. Which modes will dominate the emission depends on the coupling efficiency between the excitation source and the mode.

The dispersion relation allows us to determine which modes can play a role in the emission from these nanowires and to calculate the wavevector corresponding to each mode for a given diameter. A 1D current model, developed in Ref. 27 and applied in Ref. 23, uses the wavevectors to calculate far field emission patterns for all electromagnetic field components. The model describes the nanowire as a 1D cavity in vacuum with length \(L\); the emission is produced by a line current excited by a dipole at a given position along the wire. This simple model allows us to retrieve the expected polarization-dependent angular emission patterns for different modes at different wire diameters, which we can compare to measurements.

**CL polarimetry**

Measurements and calculations of the angle- and polarization-dependent emission intensity distributions at \(\lambda_0 = 850\) nm for central excitation of the two nanowires and clearly recognize
Figure 2: Measured (a-c, g-i) and calculated (d-f, j-l) angular emission distributions of the Cartesian field intensities at $\lambda_0 = 850$ nm for NW1 (a-f) and NW2 (g-l), as a function of azimuthal ($\varphi$) and zenithal ($\theta$) angles. The patterns were measured and calculated for central excitation of the nanowires. (a, d, g, j) show the intensity of the $E_x$ field component, (b, e, h, k) the intensity of $E_y$, and (c, f, i, l) the intensity of $E_z$ (the coordinate system is shown in the top left). The calculations for each wire determine the far field emission profiles for the TM01 mode. We use the full range of the color scale for each panel, but the intensity scales for all three field components of each nanowire are normalized to the maximum value ($E_x$ and $E_z$ are equal). The measured intensities are given in $10^6$ counts sr$^{-1}$ s$^{-1}$.

The TM01 mode as being the dominant contribution, as shown in Figure 2. For NW1 we compare the measurements (Figures 2(a–c)) to the 1D calculation for the TM01 mode (Figures 2(d–f)), displaying the Cartesian electric field intensities $|E_x|^2$, $|E_y|^2$ and $|E_z|^2$ as a function of azimuthal ($\varphi$) and zenithal ($\theta$) angles. The field orientations are indicated by the coordinate system at the left, and the wires are oriented along the y-axis. A wavevector of $k_y = 6.63 + i 1.19 \mu$m$^{-1}$ was used for the calculation, as determined from the dispersion relation and nanowire diameter. The dark blue regions around the edges of each image...
correspond to the angles at which no light is collected by the mirror. The intensity scale is chosen so as to maximize the contrast in the color scale to better view the details of the features. In the case of the calculation, the intensities are normalized to the overall maximum value for each wire. We observe excellent qualitative agreement between measurement and calculation. For $|E_x|^2$ (Figures 2(a,d)) there are four bright features at large zenithal angles, while $|E_y|^2$ (Figures 2(b,e)) displays bright emission in the center of the mirror and $|E_z|^2$ (Figures 2(c,f)) exhibits two lobes to the left and right of the polar image, in the directions of the end facets of the nanowire.

For NW2 we also observe very similar features for both measurements (Figures 2(g–i)) and calculations (Figures 2(j–l)). A wavevector of $k_y = 8.00 + i 0.50 \mu m^{-1}$ was used for the calculation in this case. For $|E_x|^2$ (Figures 2(g,j)) we observe four features at slightly higher zenithal angles than for NW1, at the corners of the angular range. $|E_y|^2$ (Figures 2(h,k)) shows the brightest intensity in the center, as for NW1, but this time we can also see intensity fringes along the vertical direction, which are due to interference between the emission from the nanowire end facets. The fringes are clearly visible in the experiment, but with lower contrast than in the calculations, which we attribute to imperfections in the mirror and the nanowire end facets, and to limitations on the angular resolution. Finally, $|E_z|^2$ (Figures 2(i,l)) again displays two lobes to the left and right, but at higher angles than for NW1, similarly to the behavior of $|E_x|^2$. In the experiment, the two lobes are asymmetric, which we attribute to the slight tapering of the wire. The emission is brighter in the direction of the thinner side. Comparing the relative intensities of calculations and measurements for both nanowires, we find that $|E_x|^2$ is weaker in the measurements than in the calculations. We ascribe this discrepancy to a lower collection efficiency at the edges of the mirror where the $|E_x|^2$ component is strongest.

Even though the two nanowires have quite different diameters, in both cases we can clearly recognize very similar polarized field distributions that show excellent qualitative agreement with calculations for the TM01 mode. From this we conclude that the emission
behavior of both NW1 and NW2 is dominated by the TM01 mode. The fundamental HE11 mode does not appear to play a major role in our case. This has been observed previously and is ascribed to the fact that the fields are localized more outside of the wire for the HE11 mode than for the TM01 mode, which shows relatively more intensity in the center of the wire, allowing it to couple more strongly. For comparison, we include calculations of the far-field emission profiles of the HE11 mode for central excitation of the thin and thick nanowires in Figure S4 of the Supporting Information. Examining all field components, we find there is much better agreement with the TM01 mode than with the HE11 mode. This confirms that the CL emission couples most efficiently to the TM01 mode. Differences between the two wires are expected, however, because for NW1 the mode is leaky \((Re(k_y) = 6.63 < k_0 = 7.39 \text{ m}^{-1})\), while for NW2 it is guided \((Re(k_y) = 8.00 > k_0 = 7.39 \text{ m}^{-1})\). To support the data, we show polarization-resolved measurements for an additional thin and thick nanowire in Figure S2 of the Supporting Information, which exhibit the same type of features for all three field components as the results shown here.

**Directional emission**

Next, we study the directional behavior of the nanowire emission for excitation off-center, near the end facets of the wires, observing a distinct difference in the directionality of the emission between NW1 and NW2, as shown in Figure 3. We compare the total intensity that both wires emit as a function of the azimuthal and zenithal angles in the case of measurements, calculations and simulations, for excitation at the left edge, center, and right edge. The edge excitation is always a few hundred nm away from the end facet, with the exact positions shown by the dashed lines in Figure 4. We compare the total intensity measurements to calculations using the dominant TM01 mode. Polarimetry measurements for select positions near the end facets (not shown here) display the same characteristic features as in Figure 2, so we do not observe a transition to a different mode at the edges. The measured
intensities differ between the wires and excitation positions, which we attribute to variations in local material quality and size of the interaction volume (due to tapering and different diameters). Here the total emission intensity is brighter when exciting the thicker ends. For the measurements on NW1, central excitation (Figure 3(b)) results in two symmetric lobes of higher intensity to the left and right, while excitation at the left edge (Figure 3(a)) leads to directional emission to the right side and excitation on the right (Figure 3(c)) leads to emission towards the left side. 1D calculations of the total emission intensity from the leaky TM01 mode qualitatively reproduce the emission behavior for excitation in the center and 300 nm from the end facets (Figures 3(d–f)). In the measurements, the electron beam excitation at the edges was \( \sim 300-500 \) nm from the end facets.

We attribute the discrepancies in the shape of the emission patterns between measurements and calculations to the fact that the excitation volume can be much larger than the electron beam width (up to a few hundred nm). This is due to electron scattering, secondary electron generation, carrier diffusion, and photon recycling, which can play a large role in such a direct band gap material.\(^{42,49,50}\) A large majority of excitations occur very close to the point of impact, but light generation will cover a larger area. The overall spatial resolution is determined by a convolution of all of these effects and will depend on the material properties. For such strongly luminescent materials as GaAs the resolution is not as good as the electron beam size but better than the full interaction volume. This is different from the calculations, which assume a point-source. The presence of the thin holey carbon substrate, which is not taken into account in the calculation, can also affect the emission, as we will now show for NW2.

The measurements on the thicker NW2 (Figures 3(g–i)) show the opposite directionality to that of NW1. Excitation at the left edge leads to emission towards the left, while excitation at the right edge produces emission towards the right. The excitation positions were 700 nm (left) and 400 nm (right) away from the end facets (see also the dashed lines in Figure 4(b)). For central excitation we observe asymmetrical emission, as was the case for Figure 2(i),
Figure 3: Measured (a-c, g-i), calculated (d-f, j-l) and simulated (m-o) angular emission distributions of the total intensity at $\lambda_0 = 850$ nm for NW1 (a-f) and NW2 (g-o). The patterns were measured and calculated for excitation at the left (a, d, g, j, m), center (b, e, h, k, n) and right (c, f, i, l, o) of the nanowires (see Figure 4 for positions). The calculations and simulations for each wire have been normalized to their maximum. The measured intensities are given in $10^6$ counts sr$^{-1}$ s$^{-1}$. The 1D calculation uses the same wire lengths as in the experiment (7.9 and 12 $\mu$m), but due to computational constraints the simulated NW2 is shorter (5 $\mu$m).

which we again attribute to the tapering of the wire that creates an inherent asymmetry in the wire and its emission properties. The tapering affects the leaky mode in the thin wire less since radiation is emitted continuously as the mode propagates along the wire. The thicker NW2 on the other hand, supports a guided mode, so light mostly escapes from the end facets and has a longer propagation length, traveling through the wire for multiple round-
trips. Since the modal properties are very sensitive to the diameter, the gradual variations along the length of the wire will affect the light more strongly.

We first compare the measurements to the 1D calculations of the (guided) TM01 mode, which do not directly take the substrate into account (Figures 3(j–l)). We represent absorption at the band edge and losses into the substrate by an imaginary part of $k_y$ of $0.50 \ i \mu \text{m}^{-1}$; this leads to an effective absorption length of $2 \ \mu \text{m}$, much larger than the TM01 wavelength ($\sim 220 \ \text{nm}$), but shorter than the NW length, thus limiting mode bouncing at the NW edges. We find that for excitation near the edges (500 nm away from the end facet, similarly to the measurement) there is a maximum in emission to the same side as in the measurements, with a weaker feature in the opposite direction. We note that in the measurements of NW2 there is also a region of higher intensity to the opposite side of the dominant emission. For central excitation, we observe quite good qualitative agreement between experiment and calculation, taking into account the asymmetry we attribute to tapering of the wire. As shown in Figure 3(k), interference fringes from the emission of both facets are expected for this long wire. These are also faintly visible in Figure 3(h).

To get a better measure for the effect of the substrate, we perform numerical simulations using COMSOL (see Methods for more details) on a 180 nm thick and 5 $\mu$ m long wire on a semi-infinite carbon substrate (Figures 3(m–o)). Due to computational constraints we did not simulate a 12 $\mu$ m long wire nor the extremely thin substrate. The simulations, however, do show good qualitative agreement with the experiment and provide insight into the role of the substrate on the emission behavior. Central excitation leads to a symmetric emission profile with highest intensity in the central region and interference fringes that are less distinct than for the 1D calculation. Excitation at the edges (500 nm from the end facets) shows emission profiles in good qualitative agreement with the measurements. There is a bright feature on the same side at high angles and a weaker spot on the opposite side. Both the 1D calculations and the simulations predict the measured directionality, which is completely opposite to the behavior of NW1. The features measured for edge excitation
closely resemble the simulation, while there is better agreement with the 1D calculation for central excitation. As the substrate is very thin, we can expect it to have a smaller effect than in the simulation that was performed for a semi-infinite substrate. The importance of the substrate as an additional loss channel does not play a large role in the case of the leaky mode ($k_y < k_0$) as there is already a strong inherent leakage. For the thicker wire, simulations without substrate show an emission directionality that is more strongly dependent on excitation position and near the edges becomes opposite to that observed in the measurements (Figure S4 and Figure S5 in the Supporting Information). We conclude that both the guided behavior of the TM01 mode and the additional loss channel due to the substrate play a role in determining the directional emission behavior of the thick nanowire.

The changing directionality observed in the measurements and calculations may be understood in an intuitive manner, when examining the differences between leaky and guided modes. For the leaky mode, leakage of the light along the nanowire dominates the emission. When exciting close to an end facet, light propagating to the edge will partially reflect back, while light going to the opposite side will propagate longer and thus leak out more, leading to a majority of the emission into the opposite direction. For the guided mode, emission from the end facets dominates, while there is loss to absorption into the substrate for light propagating along the wire, so more light will scatter out from the closest edge than from the far edge.

We can study the directional behavior of the emission as a function of the excitation position more closely, taking advantage of the high spatial resolution of CL. As discussed previously, the resolution is not limited to the electron beam size, but still remains sub-wavelength. Figure 4 shows the emission directionality for both wires when scanning the beam along their length. We determine a left-to-right ratio L-R/L+R by averaging the total intensity over all zenithal angles in 60° azimuthal wedges on the left and right sides, as these correspond to the regions of highest intensity features. The gray bands correspond to positions that are outside the wires and the dashed lines indicate the positions of the
Figure 4: Ratio of the left-to-right directional emission for NW1 (a) and NW2 (b), showing the ratio \((L-R)/(L+R)\) as a function of the electron beam position as it scans along the wire. The gray bands indicate positions that are not on the wire, while the red dashed lines indicate the positions of the left, center and right measurements shown in Figure 3. The leftwards and rightwards directional intensities were determined by averaging the total intensity over all zenithal angles in 60° azimuthal wedges \((\varphi=240–300°\) for left and \(\varphi=60–120°\) for right).

Comparing NW1 (Figure 4(a)) to NW2 (Figure 4(b)), we observe that there is no left/right directionality at the very edges for both wires, but that close to the edges the left-to-right ratio reaches a maximum which is reversed for the two wires, as expected from Figure 3. Figure S6 in the Supporting Information shows the left-to-right ratio for simulations of a thick wire, which also exhibit a maximum close to the end facet. Additionally, the simulations with substrate show better agreement with the measurements than the simulations without. The directionality we observe results from interference of waves propagating back and forth in the nanowire, which is dependent on the reflection at the end facets, absorption and leakage during propagation but also on the excitation position. This peak in
emission close to the end facet is convoluted with the interaction volume of the electrons with the material. At the very edge we do not excite as large a region, which contributes to the decrease in intensity and directionality we observe.

The change in emission directionality observed here is consistent with the additional thin and thick nanowires examined in the Supporting Information (Figure S3). Comparing all nanowires, the thickest diameter for the leaky behavior in the thinner wires is 145 nm, while the thinnest diameter for the guided behavior in the thicker wires is 170 nm. This indicates that the transition in emission directionality should occur for nanowire diameters in the range of 145-170 nm.

Conclusion

In conclusion, we have demonstrated that cathodoluminescence emission from GaAs nanowires is strongly directional and depends on the nanowire diameter. The emission excited by the electron beam couples to waveguide modes that determine the polarization and angular distribution of the outcoupled radiation. These waveguide modes are very sensitive to wire diameter, especially as they change in nature from leaky to guided when crossing the light line in air. Polarization-resolved measurements show that the TM01 mode dominates the emission from both nanowires. The thin wire supports a leaky TM01 mode, which displays emission in the direction opposite from the excited edge, while the thick wire supports a guided TM01 mode that exhibits emission in the same direction. The emission directionality switches for nanowire diameters in the range of 145-170 nm. Both the leaky/guided nature of the mode and the presence of the substrate play an important role in determining the emission directionality. Cathodoluminescence polarimetry proves to be a powerful technique to study the angular- and polarization-dependent emission properties of semiconductor nanowires or other nanostructures, with a subwavelength excitation resolution.
Methods

Sample fabrication

The GaAs nanowires were grown on a Si(111) undoped wafer via a Ga-assisted method in a DCA P600 solid-source MBE machine. Typical growth parameters are as follows: a Ga rate of 0.3 Å/s as flux of $2.5 \times 10^{-6}$ torr, a substrate temperature of 640 °C, rotation of the substrate at 7 r.p.m., and a V/III beam equivalent pressure ratio of 50. The nanowires were removed from the silicon substrate in an isopropanol solution by ultrasonic bath for 1 minute. A few drops of the isopropanol solution containing nanowires were transferred to a holey carbon TEM grid (Plano GmbH).

CL measurements

The measurements were performed in a FEI XL-30 SFEG (5 keV electron beam, $\sim$0.1 nA current) equipped with a home-built CL system. The emission excited by the electron beam is collected by an aluminium paraboloid mirror and directed to an optical setup. We measure either the spectrum using a liquid-nitrogen-cooled back-illuminated silicon CCD array (Princeton Instruments Spec-10 100B), or the angular emission profile using a Peltier-cooled back-illuminated 2D silicon CCD array (Princeton Instruments PIXIS 1024B). Using a series of six measurements of the angular CL distribution with the 2D CCD array in conjunction with a quarter-wave plate (QWP) and linear polarizer (LP) determines the full emission polarization. Each measurement was taken for a different combination of QWP and LP settings (horizontal, vertical, 45°, 135°, right- and left-handed circular). We correct for the geometrical and polarization dependent response of the paraboloid mirror on the CL emission that it redirects to the optical setup. A 40 nm bandpass color filter was used to spectrally select the measured emission at $\lambda_0 = 850$ nm. Integration times of 0.1–1 s were used depending on sample brightness. For every setting of the QWP and LP, we collected a dark reference measurement where we blank the electron beam (using the same integration
time as for the corresponding CL measurement). This reference was subtracted from the data in the post-processing stage. Possible sources of measurement errors include drift of the electron beam, bleaching/contamination which leads to a reduction in CL signal, and fluctuations in the current and/or the alignment of the mirror.

**FEM simulations**

The finite-element-method (FEM) simulations of the far field emission profiles of finite nanowires were performed using the commercial software package COMSOL Multiphysics v4.3b, using the same methods as in Ref. 27 and Ref. 23. For free-standing nanowires the simulation space consisted of a circular cylinder of length $L$ and diameter $d$ that represents the nanowire, enclosed in three concentric spheres of diameter $L + 2\lambda_0$, $L + 4\lambda_0$, and $L + 6\lambda_0$, with their centers coinciding with that of the cylinder. The innermost two spheres were set to be air ($n_{\text{air}}$), while the outermost layer was defined as a perfectly matched layer (PML) to absorb all outgoing radiation and prevent reflections. The material constants of GaAs for the cylinder were taken from Palik$^{51}$ ($n_{\text{GaAs}} = 3.6$ at $\lambda_0 = 850$ nm). A tetrahedral mesh was used, with maximum elements sizes (MES) of 25 nm in the domain of the cylinder and 160 nm for the air domains. The maximum element growth rate was set to 1.35 for all of the domains.

For nanowires on top of a carbon substrate the geometry is modified as follows. The three concentric spheres of the same diameter are divided into two semi-spherical layered domains through a plane that contains the cylinder axis and the cylinder is then shifted by $d/2$ from its original position in order to be placed on top of one of the new semi-spherical spaces, which we refer to as the substrate. The substrate was set to be amorphous carbon ($n_C = 1.987 + i 0.83$ at $\lambda_0 = 850$ nm)$^{52}$ and the rest was set to be air, except for the GaAs cylinder. As the space was divided into two different media, the material properties of the outermost PML must be the same as the adjacent medium. The MES of the tetrahedral mesh was 25 nm for the cylinder, 160 nm for the air and 90 nm for the substrate. The
maximum element growth rate was 1.35, the same as for the free-standing nanowires.

Simulations were highly memory-demanding; in the case of the nanowires of length \( L = 5 \, \mu m \) on top of the substrate, the calculations need \( \sim 400 \, GB \). Post-processing calculations were used to determine the total radiated power at the inner spherical boundary \( \sum_{\text{int}} \), defined by:

\[
P = \int_{\sum_{\text{int}}} \langle S \rangle \cdot \mathbf{n} dS
\]  

where \( \mathbf{n} \) is the outward normal unit-vector to the surface.

**Supporting Information Available**

The Supporting Information contains data from an additional two measured nanowires, calculated emission profiles for the HE11 mode, as well as simulations that compare the emission behavior with and without the substrate.

This material is available free of charge via the Internet at http://pubs.acs.org/.

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**Notes**

A.P. is co-founder and co-owner of Delmic BV, a startup company developing a commercial product based on the cathodoluminescence system that was used in this work.
Acknowledgement

The authors acknowledge Clara Osorio, Mark Knight and Toon Coenen for fruitful discussions. We also thank Mohammad Ramezani, Gözde Tüüincüoglu, Federico Matteini, and Anna Fontcuberta i Morral for providing the GaAs sample. This work is part of the “Stichting voor Fundamenteel Onderzoek der Materie (FOM)” as well as the Dutch technology foundation STW, which are financially supported by the “Nederlandse Organisatie voor Wetenschappelijk Onderzoek (NWO)” and the Dutch Ministry of Economic Affairs. It is also part of NanoNextNL, a nanotechnology program funded by the Dutch Ministry of Economic Affairs, part of an industrial partnership program between Philips and FOM, and is supported by the European Research Council (ERC). The Spanish “Ministerio de Economía y Competitividad” is also acknowledged for financial support through the grants NANOPLAS+ (FIS2012-31070) and LENSBEAM (FIS2015-69295-C3-2-P).

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Graphical TOC Entry

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